

IrDA Receiver

FEATURES

- Micro Power, 90 μ A Typical Operating Current
- 3.3V or 5V Operation
- 8-Pin SOIC Package
- 1 cm to 1 Meter IrDA Link Compliance
- Directly Interfaces to IrDA Compatible UARTS and Super I/O Chips
- Supports Data Rates from 2400 to 115.2KBits/Second
- CMOS/TTL Compatible Output
- ASK Modulation Compatible
- Drop in compatible with Irvine Sensor SIR2

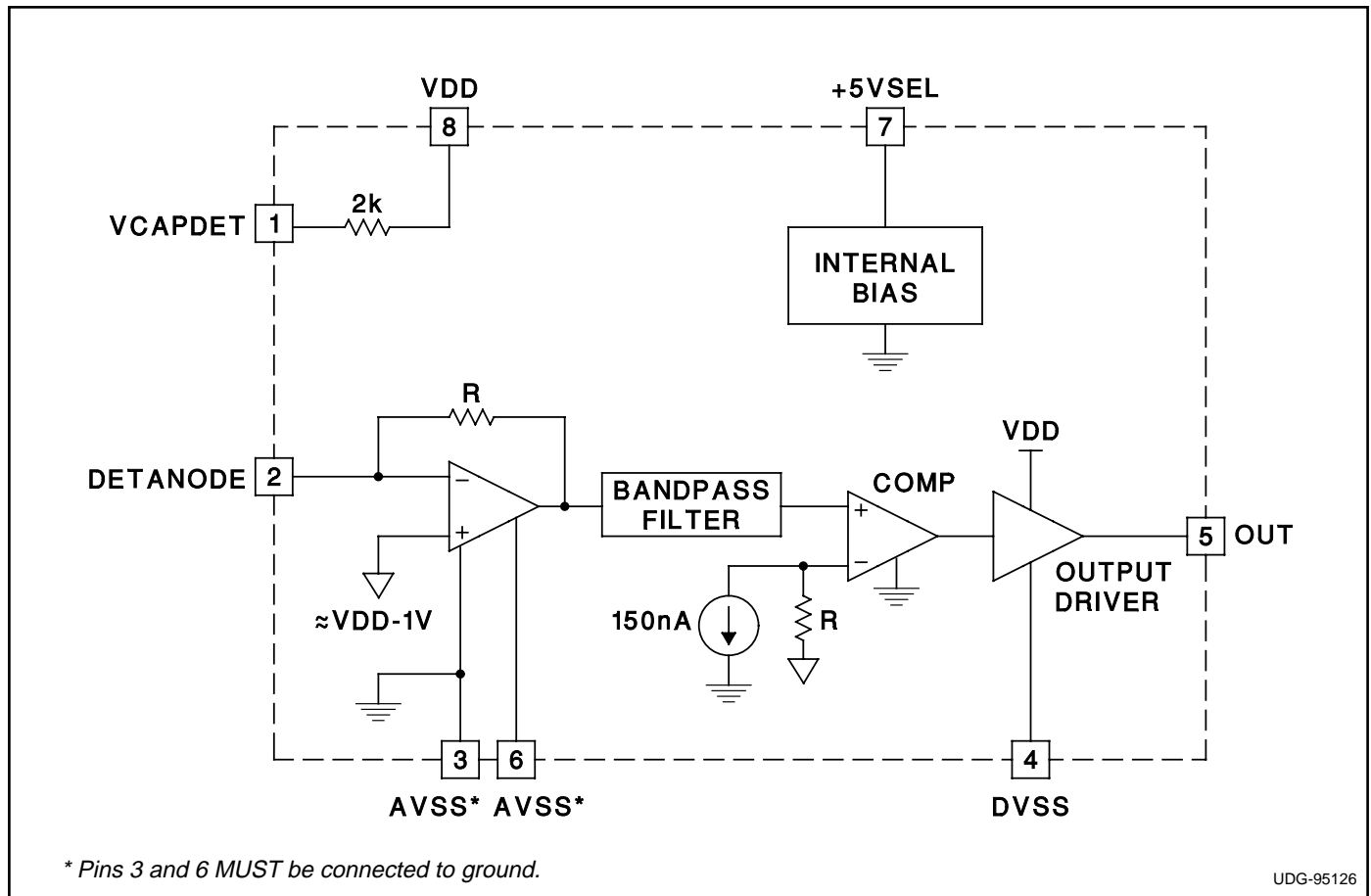
DESCRIPTION

The UCC5340 is a dual voltage, micropower, IrDA (Infrared Data Association) compliant receiver. It's high gain photodiode input amplifier incorporates a unique limiting circuit which permits operation over a very wide dynamic input range. The integrated bandpass filter includes additional limiting circuitry, further reducing device recovery time requirements, allowing the UCC5340 to directly interface with IrDA compatible detector diodes.

The output is capable of driving a 40pF load at CMOS/TTL levels for direct interfacing to IrDA compliant UARTs or Super I/O devices over a 2400BPS to 115.2kBPS range.

A control pin is provided to allow operation with either 3.3V or 5V supplies. The circuit requires only 90 μ A (nominal) operating current in either configuration. An internal 2k Ω resistor is provided for decoupling the detector supply, to minimize the number of external components required.

BLOCK DIAGRAM



UDG-95126

ABSOLUTE MAXIMUM RATINGS

VDD. -0.3V TO +6V
 Voltage at +5VSEL (r.t. GND) -0.3V to VDD
 Input Source Current to DETANODE 20mA
 Package Power Dissipation 25mW
 Operating Temperature Range 0°C to +70°C
 Storage Temperature Range -55°C to +125°C

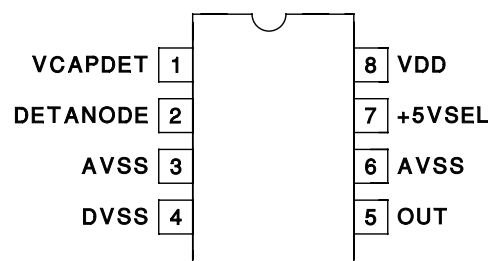
*Currents are positive into, negative out of the specified terminal.
 Consult Packaging Section of Databook for thermal limitations
 and considerations of packages.*

RECOMMENDED OPERATING CONDITIONS

VCC Voltage 3.0V to 5.5V

CONNECTION DIAGRAM

**DIL-8, SOIC-8 (Top View)
 N or D Packages**



ELECTRICAL CHARACTERISTICS Unless otherwise specified, $3.0V \leq VDD \leq 3.5V$ and $+5VSEL = GND$, or $4.5V \leq VDD \leq 5.5V$ and $+5VSEL = VDD$, $C_{DETECTOR} < 56pF$, $C_{LOAD} = 40pF$, $0^\circ C < T_A < 70^\circ C$, $T_A = T_J$.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Supply Current, I_{DD}	No Load, $I_{DETANODE} = 1\mu A$		90	150	μA
Detector Decoupling Resistance, R_{DD}			2.0	3.0	$k\Omega$
+5VSEL Input Leakage		-10		10	μA
Detector Amplifier					
I_{PDmax}	$VDD = 3V$	3	4		mA
	$VDD = 5V$	5			mA
Input Resistance, R_{IN}	$I_{DETECTOR} = 1\mu A$			20	$k\Omega$
Detection Threshold	$1\mu A$ DC Ambient Background Current		150		nA
Noise Current, I_N (rti)	Bandwidth = 0 to 650kHz			6	$nA(rms)$
Signal to Noise Ratio	$I_{DETANODE} = 400nA$	12			
Lower Bandwidth		20	40		kHz
Upper Bandwidth		0.65	1		MHz
Digital Output					
Output High, V_{OH}	$I_{LOAD} = -100\mu A$	2.4			V
Output Low, V_{OL}	$I_{LOAD} = 0.8mA$			0.4	V
AC Parameters					
Rise Time, T_r			100	200	ns
Fall Time, T_f			100	200	ns
Pulse Width, T_w	T_w , Input = $1.6\mu s$, $I_{DETANODE} = 400nA$		2		μs
Pulse Jitter, T_j				200	ns
Pulse Delay, T_d				2	μs

PIN DESCRIPTIONS

+5VSEL: +5 volt selection, strap to DVSS for 3.3 Volt or to +5 Volts for 5 Volt Operation.

AVSS: Analog Ground, VSS.

DETANODE: High side input of the transimpedance amplifier, Photodiode input.

DVSS: Digital Ground, VSS.

OUT: TTL compatible output to the IrDA Compliant UART/Super I/O.

VCAPDET: Low side of the transimpedance amplifier input, Photodiode input. It should be bypassed to AVSS with a $10\mu F$ capacitor.

VDD: +5 or +3.3 Volts supply.

APPLICATIONS INFORMATION (cont.)

The IrDA stream is a 1.6 microsecond or 3/16 th of a bit time pulse for each zero or start bit. The IrDA receiver must pick up the start bit to frame the character.

The start bit must be passed to the UART to start the framing. This is critical to get the Start bit, the IR receiver can not be in saturation from the last information transferred from the system. This requires a fast receiver AGC system, amplifiers, and filters that are not in saturation.

The receiver has to work over a very wide ambient IR level, from sunlit rooms to dark rooms. There is a wide range of background noise and ambient levels that must

be filtered out.

The receiver sees the light from the transmit side which can be at a much higher level than the received signal from another unit. The receiver must come out of saturation fast to recover to pick up the first start bit.

Units that are designed for low power will only use the 1.6 microsecond transmit pulse, others that are not concerned with power may use the 3/16 th of the bit time over the range of 2400, 9600, 19.2k, 38.4k, 57.6k, and 115.2k BPS. The shortest pulse width allowed is 1.41 microseconds, the longest pulse at 2400 BPS is 88.55 microseconds.

IrDA Standard for Speed and Tolerance

Bit Rate	Bit Rate Tolerance	Pulse Width Minimum	Pulse width 3/16 Nominal	Pulse Width Maximum
Kbits/second	% of Bit Rate	microseconds	microseconds	microseconds
2.4	± 0.87	1.41	78.13	88.55
9.6	± 0.87	1.41	19.53	22.13
19.2	± 0.87	1.41	9.77	11.07
38.4	± 0.87	1.41	4.88	5.96
57.6	± 0.87	1.41	3.26	4.34
115.2	± 0.87	1.41	1.63	2.71

APPLICATIONS HINTS

The UCC5340 low pass filter input should be bypassed with a 10μF low ESR tantalum capacitor positioned as close to VCAPDET as possible. Connections to the photodiode input should be short, surrounded by ground, and as direct as possible to reduce stray capacitance and noise pickup. To obtain maximum performance, a sepa-

rate ground plane and metal EMI shield are recommended. The optical port surface of the transmit LED and photodiode should be positioned at least one centimeter away from an IR optical window and equipment case to insure that direct sunlight does not impinge onto the photodiode surface.

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